

2N7636-GA Information

Heisener.com

Part Number 2N7636-GA

Manufacturer GeneSiC Semiconductor

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description TRANS SJT 650V 4A TO276

Package TO-276AA

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2N7636-GA Specifications

Manufacturer Part Number	2N7636-GA
Manufacturer	GeneSiC Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-276AA
Series	-
FET Type	-
Technology	SiC (Silicon Carbide Junction Transistor)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	4A (Tc) (165°C)
Drive Voltage (Max Rds On, Min Rds On)	-
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	324pF @ 35V
Vgs (Max)	-
FET Feature	-
Power Dissipation (Max)	125W (Tc)
Rds On (Max) @ Id, Vgs	415 mOhm @ 4A
Operating Temperature	-55°C ~ 225°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	TO-276
Package / Case	TO-276AA
	Report errors?

2N7636-GA Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2N7636-GA Payment Methods



















2N7636-GA Shipping Methods













If you have any question about 2N7636-GA, please do not hesitate to contact us!

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